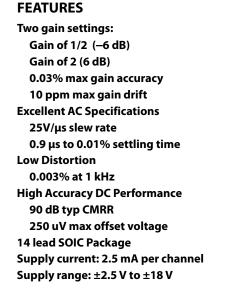


Dual-Channel Audio Difference Amplifier AD8273

Preliminary Technical Data

FUNCTIONAL BLOCK DIAGRAM



APPLICATIONS

High Performance Audio Instrumentation Amplifier Building Block Level Translator Automatic Test Equipment Sin/Cos Encoders

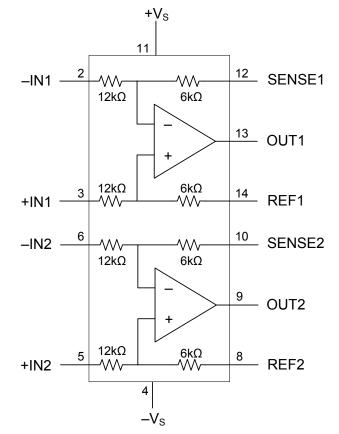


Figure 1. AD8273 Dual Difference Amplifier

Table 1. Difference Amplifiers by Category

Low Distortion	High Voltage	Single Supply Uni-directional	Single Supply Bi-directional
AD8270	AD628	AD8202	AD8205
AD8273	AD629	AD8203	AD8206
AMP03	AD8212		AD8210

GENERAL DESCRIPTION

Rev. PrA

The AD8273 is a low distortion, dual-channel amplifier with internal gain setting resistors. With no external components, it can be configured as a high performance difference amplifier (G=0.5 or 2), inverting amplifier (G=0.5 or 2) or non-inverting amplifier (G=1.5 or 3).

The AD8273 operates on both single and dual supplies and only requires 2.5 mA maximum supply current for both amplifiers. It is specified over the industrial temperature range of -40° C to $+85^{\circ}$ C and is fully RoHS compliant.

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SPECIFICATIONS

 $V_{\text{S}}=\pm 18$ V, $V_{\text{REF}}=0$ V, $T_{\text{A}}=25^{\circ}\text{C},$ G=1/2, $R_{\text{L}}=2$ k\Omega, unless otherwise noted.

Table 2.

Parameter	Conditions	Min	Тур	Max	Unit
DYNAMIC PERFORMANCE					
Bandwidth			12		MHz
Slew Rate			25		V/µs
Settling Time to 0.1%	10V Step on output, C∟=100 pF		0.7		μs
Settling Time to 0.01%	10V Step on output, C∟=100 pF		0.9		μs
Channel Separation	f = 1 kHz		130		dB
NOISE/DISTORTION ¹					
THD + Noise	f = 1 kHz, V _{IN} = 10 Vrms		0.003		%
Noise Floor, RTO	20 kHz BW		-120		dBu ²
Output Voltage Noise (referred to input)	f = 20 Hz to 20 kHz		3		μVrms
	f = 1 kHz		20		nV/√Hz
GAIN					
Gain Error				0.03	%
Gain Drift			1	10	ppm/°C
Gain Nonlinearity			10		ppm
INPUT CHARACTERISTICS					
Offset ³			200	400	μV
vs. Temperature			2		μV/°C
vs. Power Supply			5	20	μV/V
Common Mode Rejection Ratio	$V_{CM}=\pm 18V$, $R_s=0\Omega$, referred to input	77	86		dB
Input Voltage Range		-Vs-0.5		+Vs+0.5	V
Impedance					
Differential			24		kΩ
Common Mode ⁴			9		kΩ
OUTPUT CHARACTERISTICS					
Output Swing		-Vs+1.5		+ Vs -1.5	V
Short circuit current limit			60		mA
Capacitive Load Drive			100		pF
POWER SUPPLY					
Supply Current (per Amplifier)				2.5	mA
TEMPERATURE RANGE					
Specified Performance		-40		85	

¹ Includes amplifier voltage noise, resistor network voltage noise, and amplifier current noise through resistor network ² dBu = 20log(Vrms/0.7746)

- ³ Includes effects of amplifier's input bias and offset currents

 4 Calculated looking into both inputs. Common mode impedance looking into only one input is 18 $k\Omega$

Table 3.

Parameter	Rating				
Supply Voltage	TBD				
Output Short-Circuit Current	Indefinite				
Input Voltage (Common Mode)	TBD				
Differential Input Voltage	TBD				
Storage Temperature Range	–65°C to +130°C				
Specified Temperature Range	–40°C to +85°C				
Thermal Resistance θ_{JA}	120 °C/W				
Thermal Resistance θ_{JC}	36 °C/W				
Package Glass Transition Temperature (T_G)	130°C				

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions may affect device reliability.

Maximum Power Dissipation

The maximum safe power dissipation for the AD8273 is limited by the associated rise in junction temperature (T_J) on the die. At approximately 130°C, which is the glass transition temperature, the plastic changes its properties. Even temporarily exceeding this temperature limit may change the stresses that the package exerts on the die, permanently shifting the parametric performance of the amplifiers. Exceeding a temperature of 130°C for an extended period can result in a loss of functionality.

ESD CAUTION

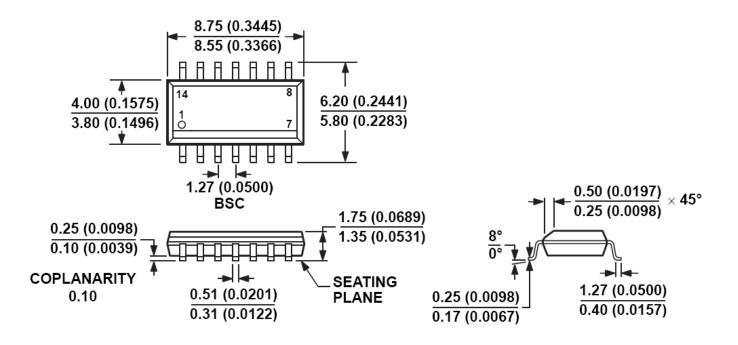
ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



OUTLINE DIMENSIONS



14-Lead Standard Small Outline Package [SOIC_N] Narrow Body (R-14) Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MS-012-AB

Figure 2. 14 Lead Narrow Body SOIC package



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